

Product data sheet

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ESD5V0S2BT-MS

Features

- ♦ 150 Watts peak pulse power (tp = 8/20µs)
- Transient protection for high speed data lines to IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact) IEC 61000-4-4 (EFT) 40A (5/50ns)
- ♦ Working voltages : 5V
- Protects two bidirectional line
- Low operating and clamping voltages
- Solid-state silicon avalanche technology

Applications

- Notebooks, Desktops, Servers and Video Graphics Cards
- USB Power & Data Line Protection
- Monitors and Flat Panel Displays
- I²C Bus Protection
- Portable Instrumentation
- Set Top Box

Electrical Characteristics@ Ta=25°C unless otherwise

	Vdrm	Idrm	Vbr	lr	Vc	lpp	Vc	Ірр	СО
P/N	V	μA	V	mA	V	А	V	А	pF
		MAX	MIN		MAX		MAX		TYP
ESD5V0S2BT-MS	5	1	5.5	1	9.8	1	15	12	50

Maximum Rating @ Ta=25°C unless otherwise specified

Symbol	Parameter	Ratings	Units
Ррк	Peak Pulse Power (tp = 8/20µs)	150	Watts
Τι	Lead Soldering Temperature	260(10sec.)	°C
TJ	Operating Temperature	-55 to +125	°C
Тѕтс	Storage Temperature	-55 to +150	°C

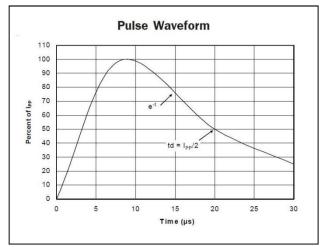
SOT-23

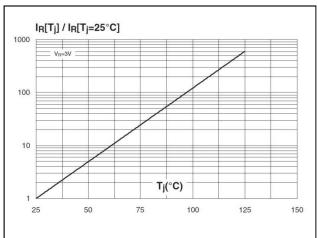


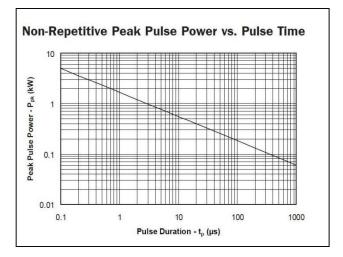
ESD5V0S2BT-MS HF

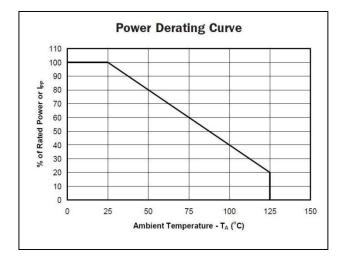
Semiconductor Compiance

Typical Characteristics@ Ta=25°C unless otherwise specified



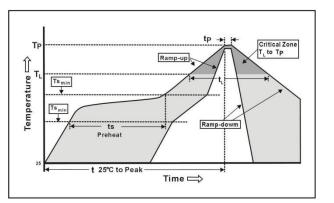






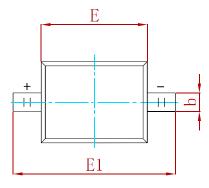
Soldering Parameters

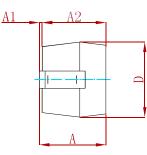
Reflow Condition		Fb – Free assembly	
	- Temperature Min (T _{s(Min)})	150°C	
Pre Heat	- Temperature Max (T _{s(Max)})	200°C	
	-Time (Min to max) (t _s)	60 – 180 secs	
Average ra (T _L) to pea	amp up rate (Liquidus) Temp k	3°C/second Max	
T _{S (Max)} to T _L - Ramp-up Rate		3°C/second Max	
Reflow	-Temperature (T _L) (Liquidus)	217°C	
	-Temperature (t _l)	60 – 150 seconds	
Peak Temp	perature (T _P)	250 ^{+0/-5} °C	
Time within 5°C of actual peak Temperature (t _p)		20 – 40 seconds	
Ramp-dov	/m Rate	6°C/second Max	
Time 25°C	to peak Temperature (T _p)	8 minutes Max.	
Do not exc	eed	260°C	

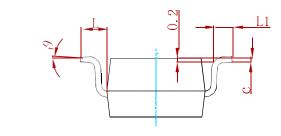




PACKAGE MECHANICAL DATA

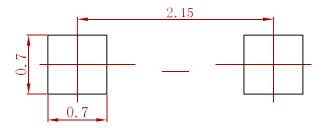






Cumhal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A		1.000		0.039	
A1	0.000	0.100	0.000	0.004	
A2	0.800	0.900	0.031	0.035	
b	0.250	0.350	0.010	0.014	
с	0.080	0.150	0.003	0.006	
D	1.200	1.400	0.047	0.055	
E	1.600	1.800	0.063	0.071	
E1	2.550	2.750	0.100	0.108	
L	0.475	REF.	0.019 REF.		
L1	0.250	0.400	0.010	0.016	
θ	0°	8°	0°	8°	

Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:± 0.05mm.

3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
ESD5V0S2BT-MS	SOT-23	3000



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